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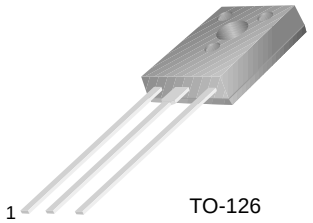
KSC2752

High Speed
High Voltage Swiching Industrial Use



1

TO-126

1. Emitter 2.Collector 3.Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	500	V
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	7	V
I_C	Collector Current (DC)	0.5	A
I_{CP}	*Collector Current (Pulse)	1	A
I_B	Base Current (DC)	0.25	A
P_C	Collector Dissipation (T_a=25°C)	1	W
P_C	Collector Dissipation (T_C=25°C)	10	W
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	- 55 ~ 150	°C

* PW≤300μs, Duty Cycle≤10%

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
V_{CEO}(sus)	Collector-Emitter Sustaining Voltage	I_C = 0.3A, I_{B1} = 0.06A, L = 10mH	400		V
V_{CEX}(sus)1	Collector-Emitter Sustaining Voltage	I_C = 0.3A, I_{B1} = -I_{B2} = 0.06A V_{BE}(off) = -5V, L =10mH, Clamped	450		V
V_{CEX}(sus)2	Collector-Emitter Sustaining Voltage	I_C = 0.6A, I_{B1} = 0.2A, I_{B2} = -0.06A V_{BE}(off) = -5V, L = 10mH, Clamped	400		V
I_{CBO}	Collector Cut-off Current	V_{CB} = 400V, I_E = 0		10	μA
I_{CER}	Collector Cut-off Current	V_{CE} = 400V, R_{BE} = 51Ω, T_C= 125°C		1	mA
I_{CEX1}	Collector Cut-off Current	V_{CE} = 400V, R_{BE}(off) = -1.5V		10	μA
I_{CEX2}	Collector Cut-off Current	V_{CE} = 400V, R_{BE}(off) = -1.5V @ T_C= 125°C		1	mA
I_{EBO}	Emitter Cut-off Current	V_{EB} = 5V, I_C = 0		10	μA
h_{FE1} h_{FE2}	* DC Current Gain	V_{CE} = 5V, I_C = 0.05A V_{CE} = 5V, I_C = 0.3A	20 10	80	
V_{CE}(sat)	* Collector-Emitter Saturation Voltage	I_C = 0.3A, I_B = 0.06A		1	V
V_{BE}(sat)	* Base-Emitter Saturation Voltage	I_C = 0.3A, I_B = 0.06A		2	V
t_{ON}	Turn ON Time	V_{CC} = 150V, I_C = 0.3A I_{B1} = -I_{B2} = 0.06A, R_L = 500Ω PW = 50μs, Duty Cycle≤2%		1	μs
t_{STG}	Storage Time			2.5	μs
t_F	Fall Time			1	μs

* Pulse Test: PW≤350μs, Duty Cycle≤2% Pulsed

h_{FE} Classification

Classification	R	O	Y
h_{FE1}	20 ~ 40	30 ~ 60	40 ~ 80

Typical Characteristics

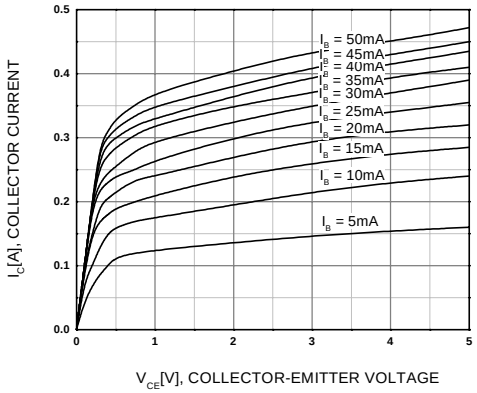


Figure 1. Static Characteristic

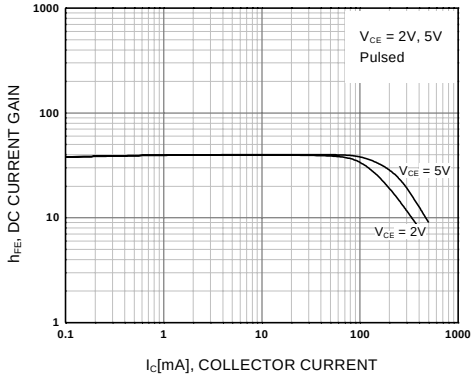


Figure 2. DC current Gain

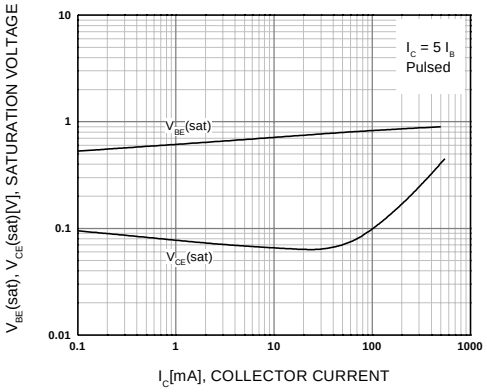


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

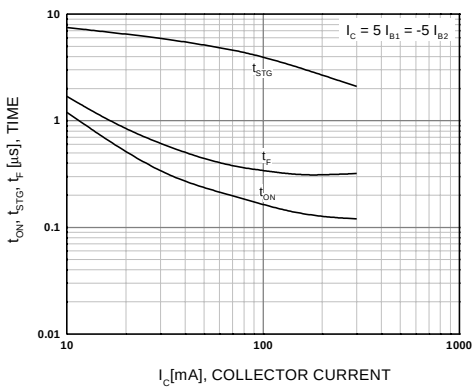


Figure 4. Switching Time

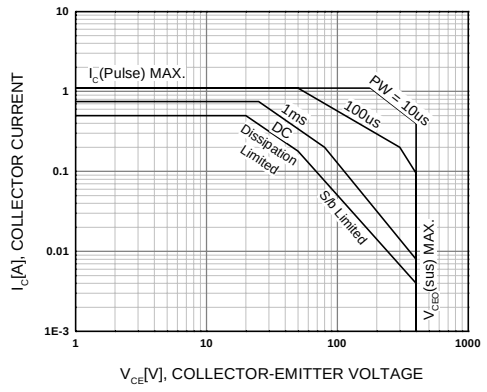


Figure 5. Safe Operating Area

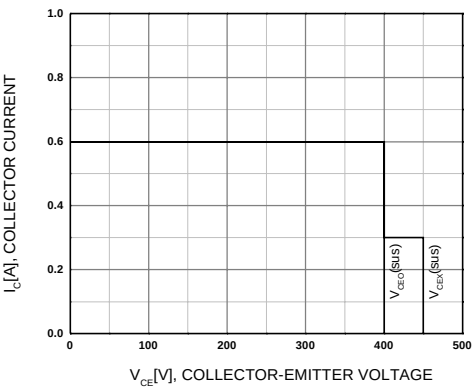


Figure 6. Reverse Bias Safe Operating Area

Typical Characteristics (Continued)

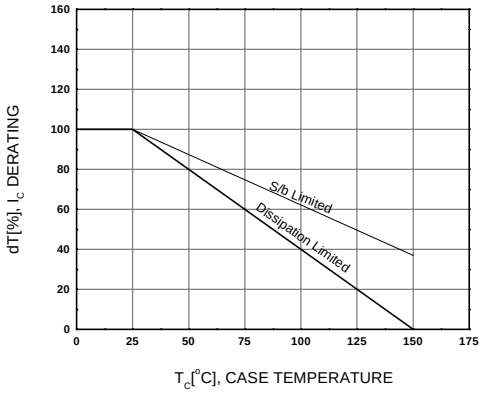


Figure 7. Derating Curve of Safe Operating Area

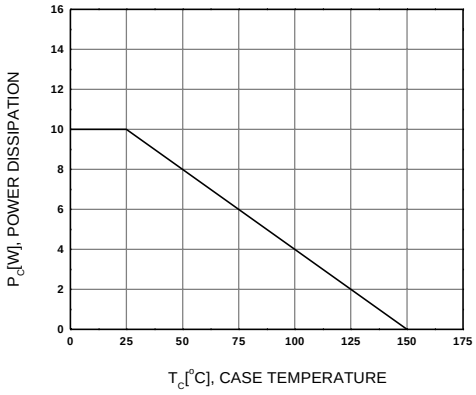
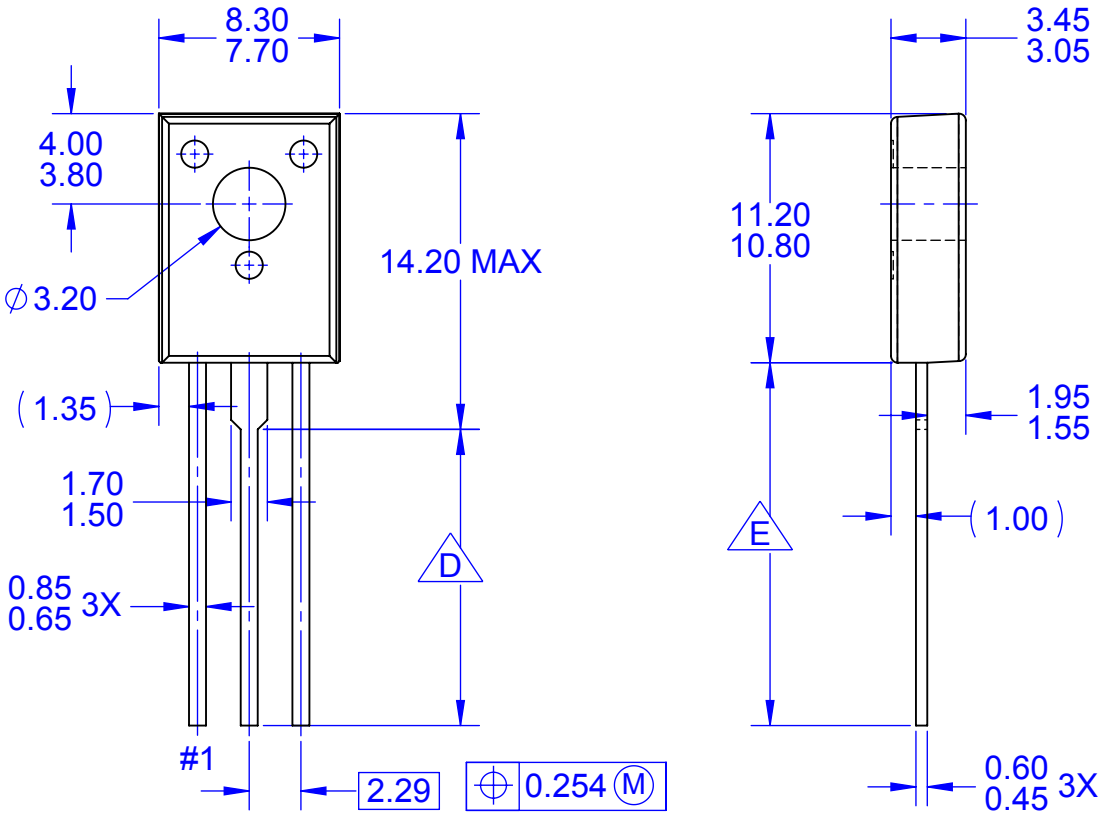
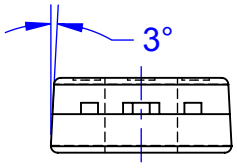


Figure 8. Power Derating



TOP VIEW

SIDE VIEW



FRONT VIEW

PRODUCTION CODE	TERMINAL LENGTH "D"	TERMINAL LENGTH "E"
TSSTU	3.45 - 4.05	6.45-7.45
TSTU	2.36 - 2.96	5.36-6.36
NONE (STD LENGTH)	12.76 - 13.36	15.76-16.76

NOTES:

A. NO INDUSTRY STANDARD APPLIES TO THIS PACKAGE
B. ALL DIMENSIONS ARE IN MILLIMETERS
C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR PROTRUSIONS

△D FOR TERMINAL LENGTH "D", REFER TO TABLE

△E FOR TERMINAL LENGTH "E", REFER TO TABLE

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